HD Communications Corp.

HD32112
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Rack mounted system
Class AB linear GaN design
Instantaneous wide bandwidth
Suitable for all single channel modulations standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	850 - 1450 MHz	
Power Output @ Saturation	1000 Watt Min	CW
Power Gain	60 dB Min	
Power Gain Flatness	2.0 dB p-p Max	Constant input power
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	50dBm/Tone, Δ = 1MHz
Harmonics	<-20 dBc Typ	At rated output power
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	180 - 240 VAC	
Power Consumption	3.2 KW Max	
Input Power Protection	+5 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

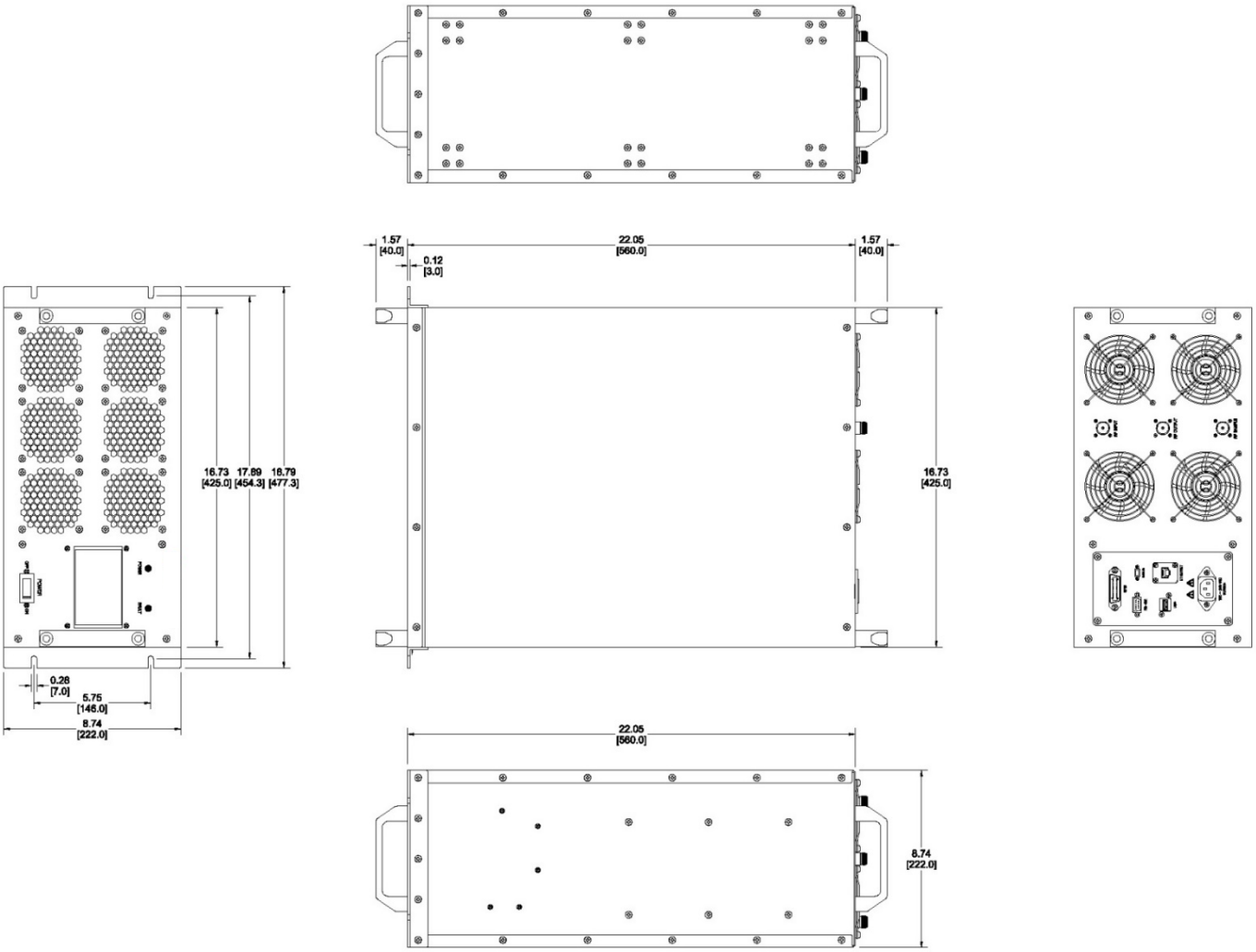
Parameter	Specification	Notes
Dimensions W x H x D	430 x 222 x 560 mm	5U rack chassis
Weight	30 kg. Max	
RF Connectors In / Out	Type-N Female / 7/16 DIN	Front Panel Standard
AC Power / Interface	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Variable Speed Fan Cooling	54dBA Noise level
OPTIONAL: Digital Monitor & Control: FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

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OUTLINE DRAWING



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